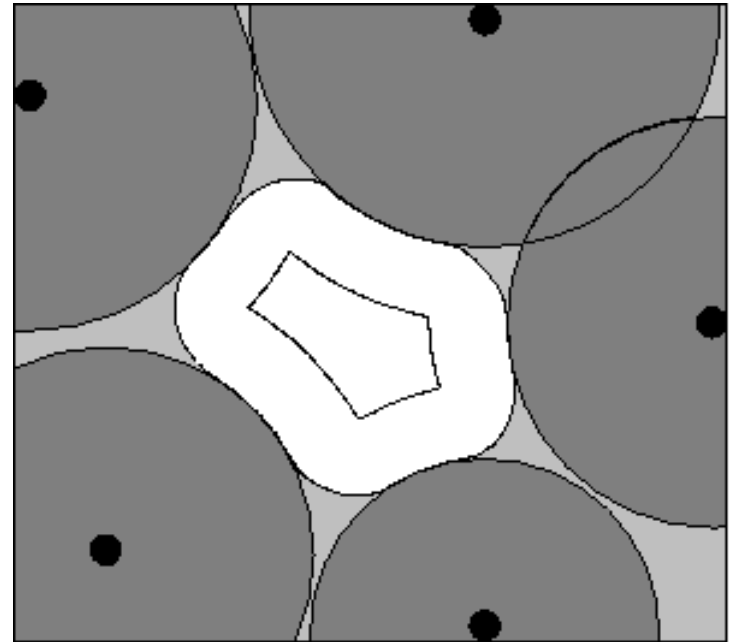


PLATON/SQUEEZE

Ton Spek
Bijvoet Center
Utrecht University,
The Netherlands.

PLATON Workshop

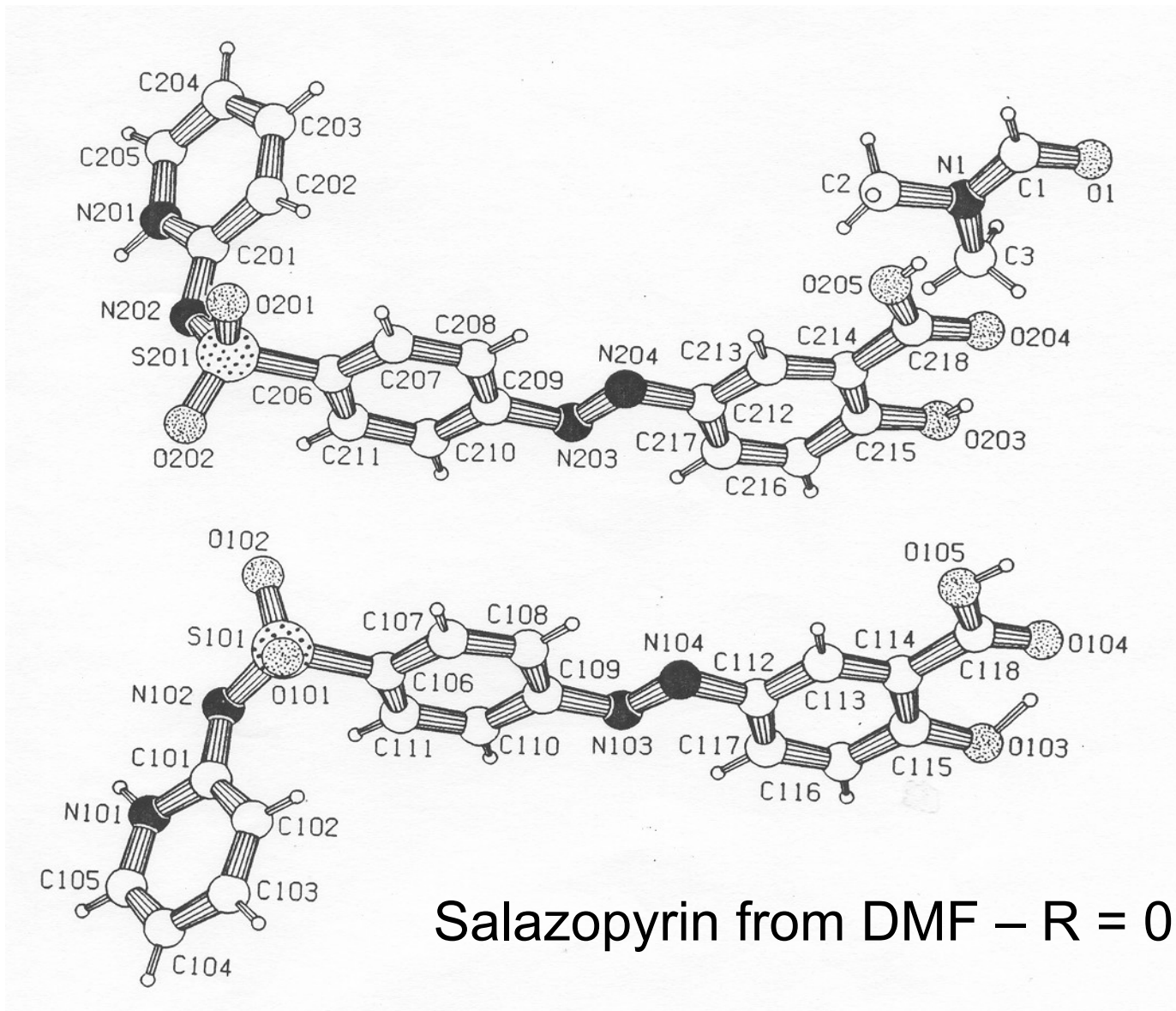
Chicago, 24-July-2010



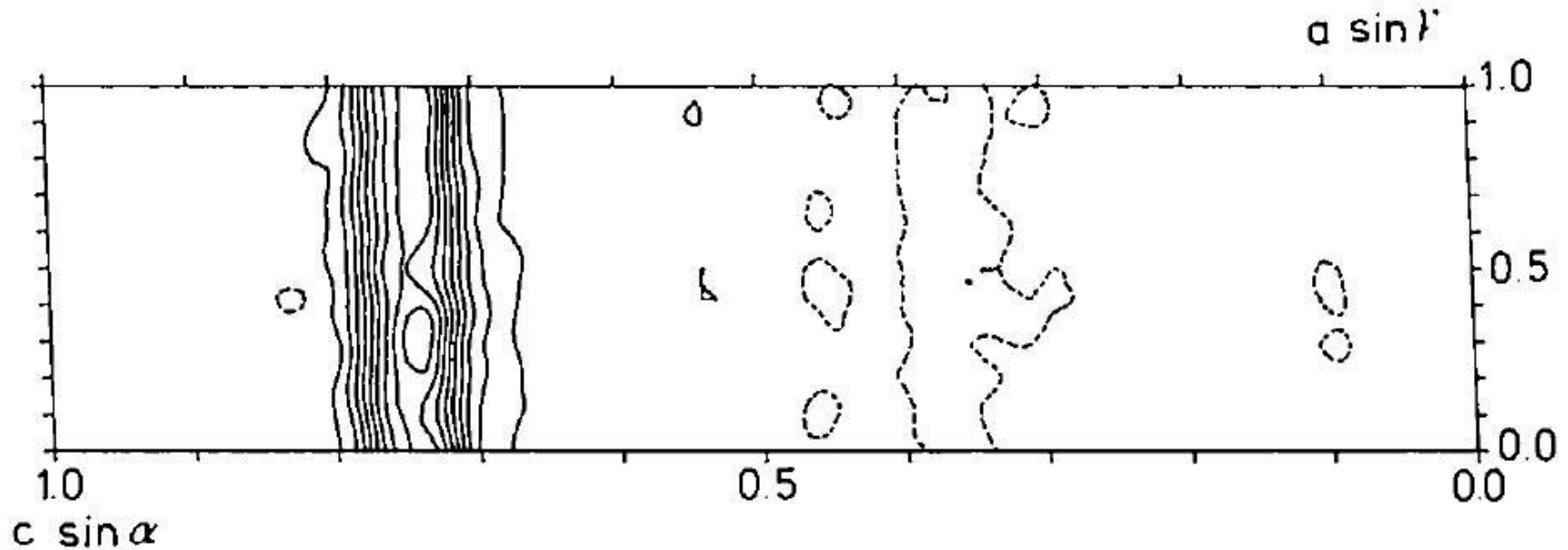
The Disordered Solvent Problem

- Molecules of interest often co-crystallize (only) with the inclusion of a suitable solvent molecule.
- Solvent molecules often fill voids in a structure with little interaction and are often located on symmetry sites and with population less than 1.0
- Sometimes even the nature of the (mixture) of included solvent(s) is unclear.
- Inclusion of the scattering contribution of the solvent to the structure factors can be done either with an (elaborate) disorder model or with the SQUEEZE approach.

THE MOLECULE THAT INVOKED THE BYPASS/SQUEEZE TOOL



Structure Modelling and Refinement Problem for the Salazopyrin Structure

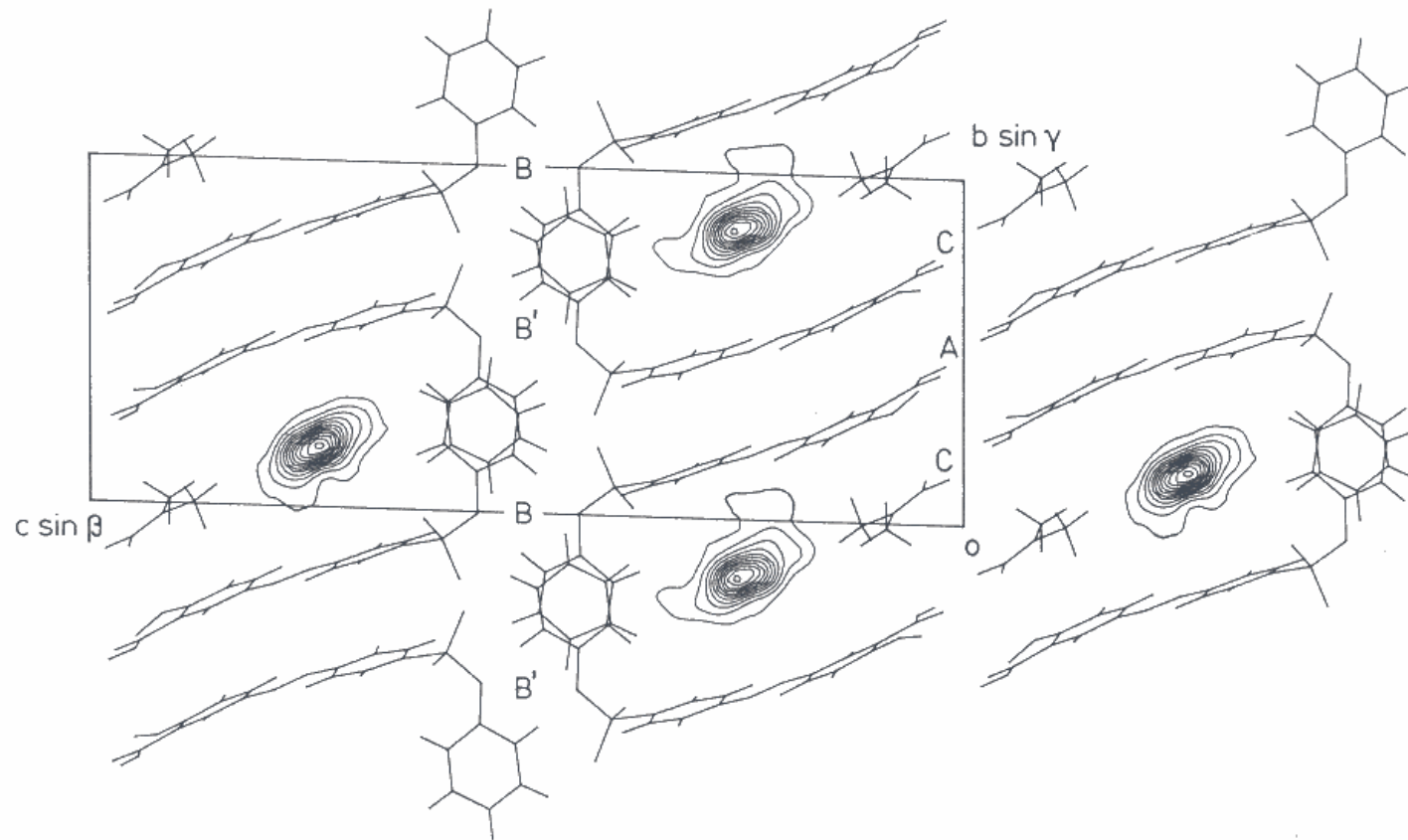


Difference Fourier map shows channels with continuous density rather than maxima

How to handle this in the Refinement ?

SQUEEZE !

Looking down the Infinite Channels in the Salazopyrin Structure

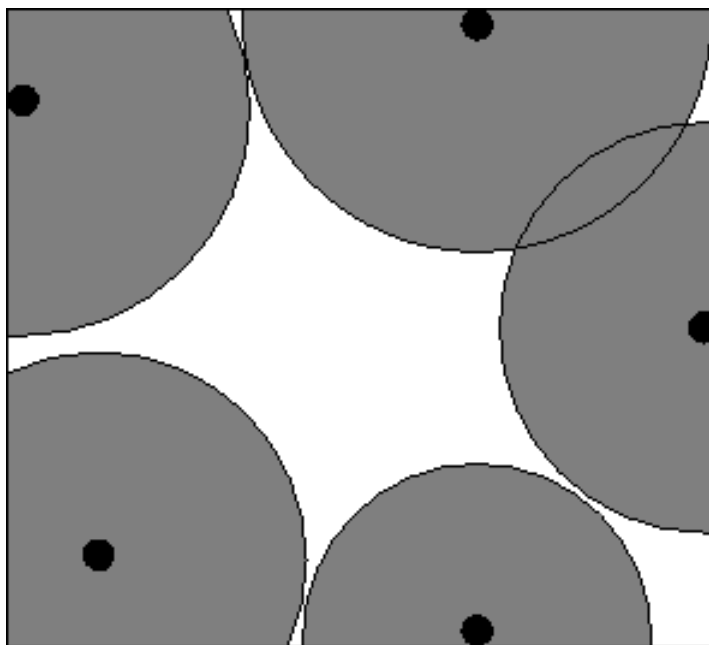


The Problem: Peak Search algorithms will not always tell about the residual density. We need special tools to detect voids in a modeled structure.

Automated Detection of Solvent Accessible Voids

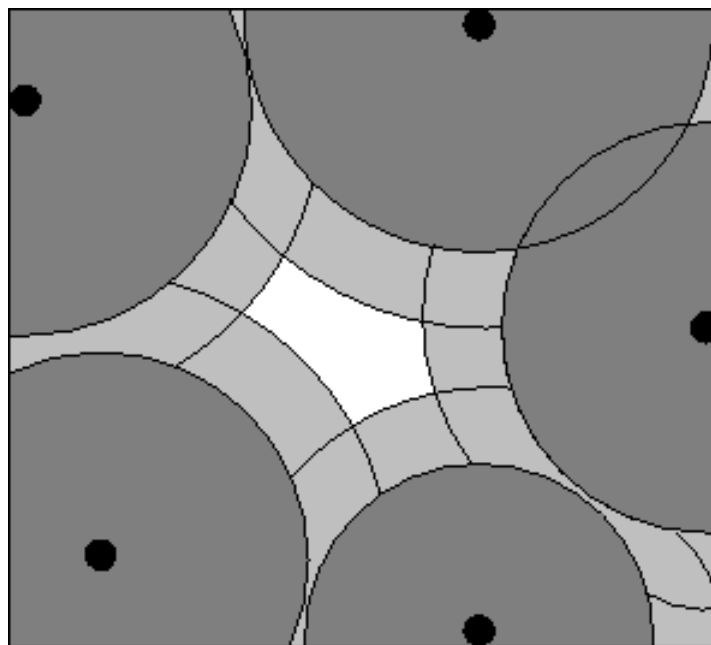
- A typical crystal structure has only in the order of 65% of the available space filled.
- The remainder volume is in voids (cusps) in-between atoms (too small to accommodate an H-atom)
- **Solvent accessible voids** can be defined as regions in the structure that can accommodate at least a sphere with radius 1.2 Angstrom without intersecting with any of the van der Waals spheres assigned to each atom in the structure.
- Next Slide: Void Algorithm: Cartoon Style →

LOCATE SOLVENT ACCESSIBLE VOID



STEP #1 – EXCLUDE VOLUME INSIDE THE
VAN DER WAALS SPHERE

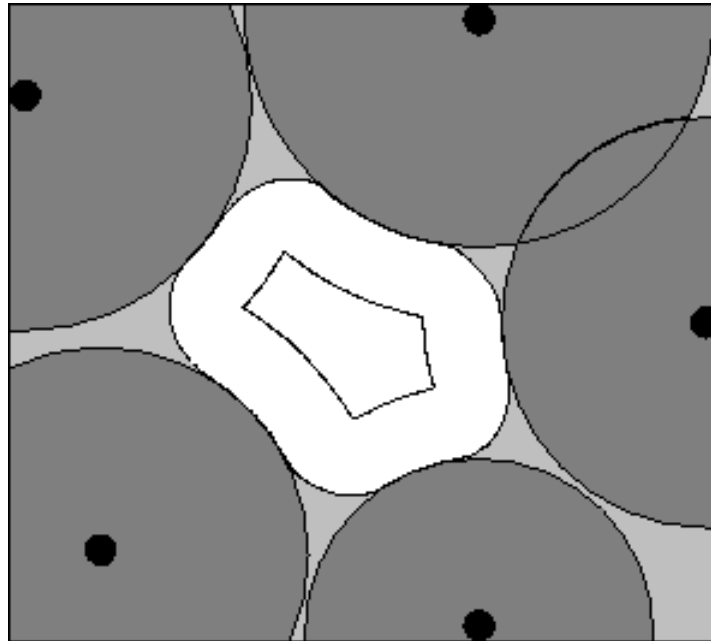
LOCATE SOLVENT ACCESSIBLE VOID



White Area:
Ohashi Volume.
Location of possible
Atom centers

STEP # 2 – EXCLUDE AN ACCESS RADIAL VOLUME
TO FIND THE LOCATION OF ATOMS WITH THEIR
CENTRE AT LEAST 1.2 ANGSTROM AWAY

LOCATE SOLVENT ACCESSIBLE VOID



STEP # 3 – EXTEND INNER VOLUME WITH POINTS WITHIN
1.2 ANGSTROM FROM ITS OUTER BOUNDS

VOID SEARCH ALGORITHM

- Move a probe with radius 1.2 Ang over a fine (0.2 Angstrom) grid through the unit cell.
- Start a new void when a grid point is found that is at least 1.2 Angstrom outside the van der Waals surface of all atoms.
- Expand this void with connected grid points with the same property until completed.
- Find new starting grid point for the next void until completion.
- Expand the 'Ohashi' volumes with grid points within 1.2 Angstrom to surface grid points.

Search for and Analysis of Solvent Accessible Voids In the Structure

Area	#GrId	Polnt	VolPerc.	Vol (A 3)	X(av)	Y(av)	Z(av)	Elgenvector(frac)	SLg(Ang)
1	20126	[4072]	4	156 [31.6]	0.000	0.184	0.750	1 1.000 -0.003 0.520 2 -0.502 -0.002 1.000 3 -0.001 -1.000 -0.002	1.74 1.55 1.35
2	20134	[4072]	4	156 [31.6]	0.500	0.316	0.250	1 1.000 -0.006 0.521 2 -0.503 -0.002 1.000 3 -0.003 -1.000 -0.001	1.74 1.55 1.35
3	20125	[4072]	4	156 [31.6]	0.500	0.684	0.750	1 1.000 -0.008 0.522 2 -0.504 -0.005 1.000 3 -0.003 -1.000 -0.004	1.74 1.55 1.35
4	20131	[4072]	4	156 [31.6]	0.000	0.816	0.250	1 1.000 -0.003 0.523 2 -0.505 -0.002 1.000 3 -0.001 -1.000 -0.002	1.74 1.55 1.35

Listing of all voids in the unit cell

The numbers in [] refer to the Ohashi Volume

EXAMPLE OF A VOID ANALYSIS

SOLV MENU

Stereo Opts

DotsContour

ViewX0

ViewY0

ViewZ0

Reverse-B&W

VoidAxes

UnitSymPack

Resd012..

UnitFill

Void0123...

UnitCellBox

Show-Mol

Ohashi-Vol

LabelCell

Label -Hat+

LabelSize >

<<-RotZ>>

<<-RotY>>

<<-RotX>>

Color

Decoration

EPS-File

End

Exit

MenuActive

INSTRUCTION INPUT via KEYBOARD or LEFT-MOUSE-CLICKS (HELP with RIGHT CLICKS)

Solvent Accessible Void Found (See Listing for Details)

>> Continue (Y/N/[Y])

VOID APPLICATIONS

- Detection of (possibly missed) Solvent Accessible Voids in a Structure
- Calculation of the Kitaigorodskii Packing Index
- Determination of the available space in solid state reactions (Ohashi)
- Determination of pore volumes, pore shapes and migration paths in micro-porous crystals
- As part of the SQUEEZE routine to handle the contribution of disordered solvents in a crystal structure refinement.

SQUEEZE

- Takes the contribution of disordered solvents to the calculated structure factors into account by back-Fourier transformation of density found in the 'solvent accessible volume' outside the ordered part of the structure (iterated).
- Two Options:
- Refine with **SHELXL** using the solvent free .hkl
- Or use **CRYSTALS** using the SQUEEZE solvent contribution to $F(\text{calc})$ and the full $F(\text{obs})$.
- **Note: SHELXL lacks option for fixed contribution to Structure Factor Calculation.**

Informal Theory of the SQUEEZE Procedure

$$F_H = \int_V \rho(\vec{r}) e^{2\pi i \vec{H} \cdot \vec{r}} dV$$

$$= \int_V (\rho^M(\vec{r}) + \rho^S(\vec{r})) e^{2\pi i \vec{H} \cdot \vec{r}} dV$$

$$\rho^M(\vec{r}) = \sum_{j=1}^N \rho(\vec{r} - \vec{r}_j)$$

$$F_H^M = \sum_{j=1}^N f_j e^{2\pi i \vec{H} \cdot \vec{r}_j}$$

$\approx \Delta \rho(\vec{r}_k)$ on grid

$$F_H^S = V_g \sum_S \Delta \rho(\vec{r}_k) e^{2\pi i \vec{H} \cdot \vec{r}_k}$$

$$F_H^C = F_H^M + F_H^S \Rightarrow$$

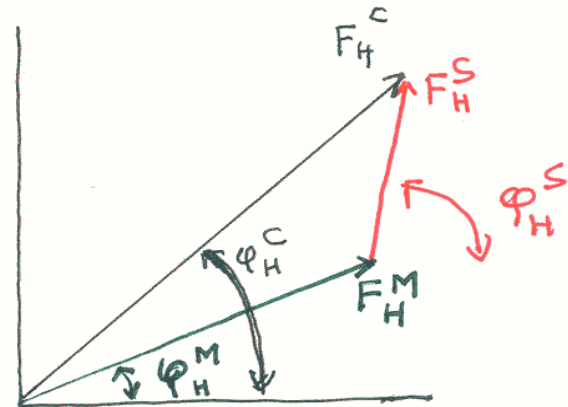


M = Ordered

S = Solvent

Iterate (Initially $\rho_H^S = \rho_H^M$)

$$\Delta \rho(\vec{r}) = \frac{1}{V} \sum_H (|F_H^0| e^{i\varphi_H^C} - |F_H^M| e^{i\varphi_H^M}) e^{-2\pi i \vec{H} \cdot \vec{r}} + \frac{F_0^S}{V}$$



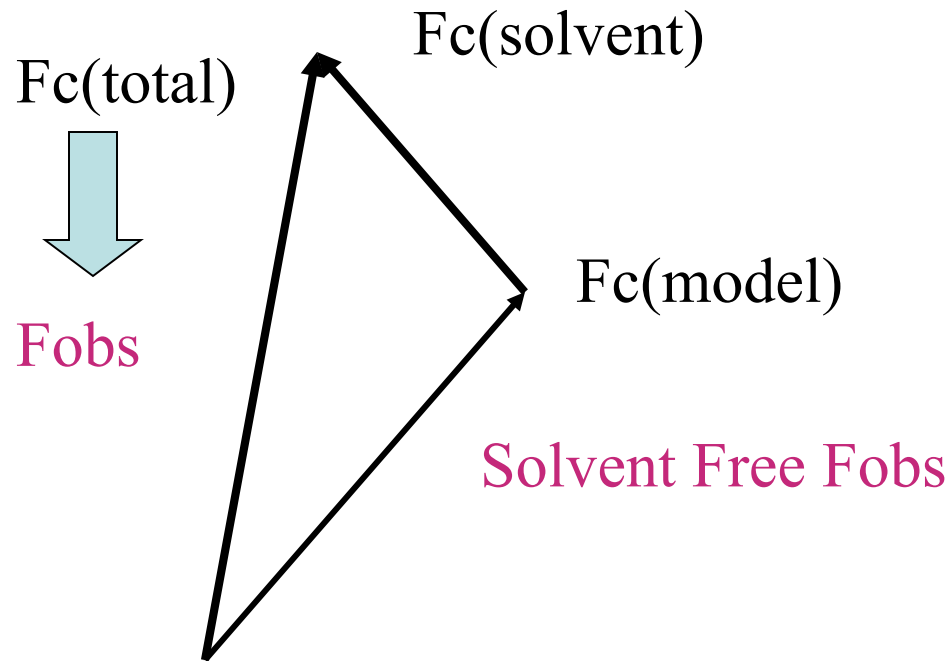
Solvent Free
Electron Count

$$F_H^0 : F_H^{0'} = |F_H^0| e^{i\varphi_H^C} - |F_H^S| e^{i\varphi_H^S}$$

$$: V_g \sum_S \Delta \rho(\vec{r}_k)$$

SQUEEZE

In the Complex Plane



Black: Split F_c into a discrete and solvent contribution

Red: For SHELX refinement, temporarily subtract recovered solvent contribution from F_{obs} .

SQUEEZE Algorithm

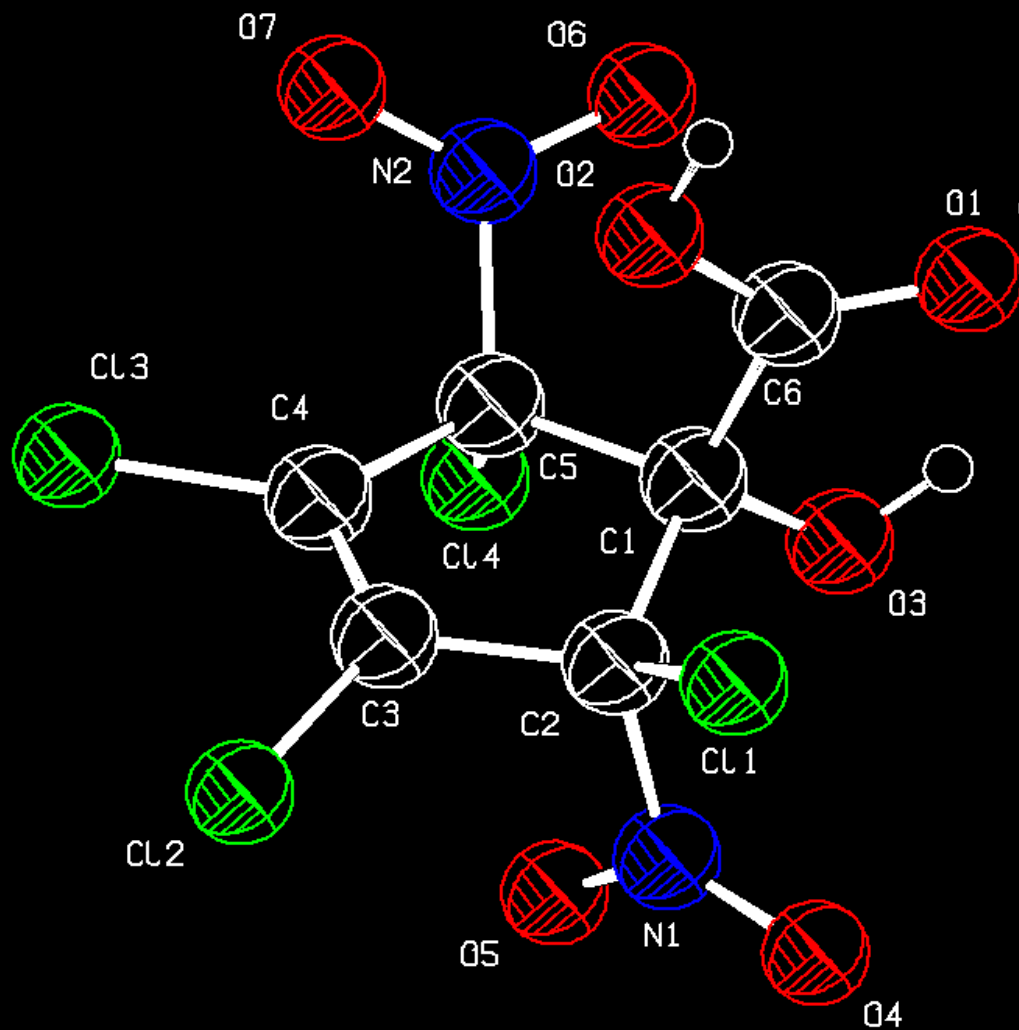
1. Calculate difference Fourier map (FFT)
2. Use the VOID-map as a mask on the FFT-map to set all density outside the VOID's to zero.
3. FFT^{-1} this masked Difference map \rightarrow contribution of the disordered solvent to the structure factors
4. Calculate an improved difference map with $F(\text{obs})$ phases based on $F(\text{calc})$ including the recovered solvent contribution and $F(\text{calc})$ without the solvent contribution.
5. Recycle to 2 until convergence.

Test Example with Calculated Data

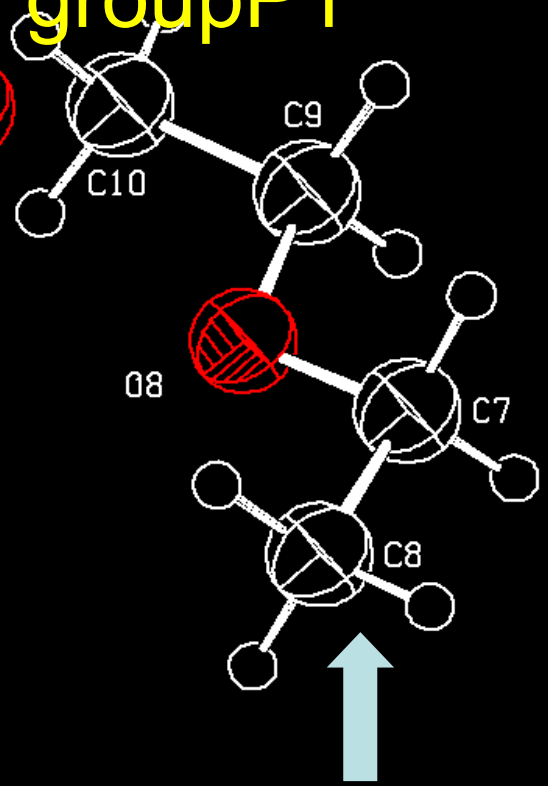
- ‘Observed Data’ were calculated from the published coordinates.
- The ether molecule was subsequently removed
- SQUEEZE was tested to see whether the method recovers the ether contribution to the structure factors.

Test Data From CSD: J. Aust. Chem. (1992),45,713

Prob = 50



Space group P1



LEFT OUT FOR SQUEEZE TEST

INSTRUCTION INPUT via KEYBOARD or LEFT-MOUSE-CLICKS (HELP with RIGHT CLICKS)

ORTEP	MENU
OptionMenus	
Stereo Opts	
Incl-HAtoms	
DeleteAtoms	
Probability	
CalcCoordn	
DisAnglTors	
JoinDashDet	
DefineToEnd	
ViewOptions	
NoDisorder	
Label -Hat+	
MoveLabel	
LabelSize >	
DeleteLabel	
IncludLabel	
Resd012..	
CRotY >>	
<<-RotZ++>	
<<-RotY++>	
<<-RotX++>	
Prev	Next
Decoration	
b&w-EPS-col	
PLUTON	End
Exit	
MenuActive	

Search for and Analysis of Solvent Accessible Voids In the Structure

Area	#Gr	LdPa	Lnt	VolPerc.	Vol (A ³)	X(av)	Y(av)	Z(av)	El	genvector (frac)	SLg (Ang)
1	21054	[3308]	34	144	[22.6]	0.178	0.014	0.183	1
									2	0.120	1.000
									3	0.980	-0.903
										1.000	1.000
										0.275	-0.605
											1.27

A solvent accessible volume of 144 Ang**3 is found

This volume will be used as a mask on the difference
Fourier map following the SQUEEZE recycling method

PLATON MENU

OptionMenu

NoMove

Color

Organic

Round

Parentheses

Label-Alias

R/S-Determ

Norm-H-bond

NoSymm

Join-Expand

LstARU RCel

LstCellSymm

ListAtoms

ListBonds

LstFlagRadi

Exclude H

MinQPeakHgt

MinQPeakDis

Q-Peak-Incl

KeyInstruct

Prev Next

SAVE-InstrS

ENTRY-LIST

Reset End

Exit

MenuActive

INSTRUCTION INPUT via KEYBOARD or LEFT-MOUSE-CLICKS (HELP with RIGHT CLICKS)

Solvent Accessible Void Found (See Listing for Details)

>> Hit RETURN to Continue

PLATON/SQUEEZE

Cycle	R(F)	Nref(HemL)	R(F)	.gt.	4Slg	Nref	EL/Cell
1	0.180	1943	0.159		1938		0
2	0.085	1943	0.075		1938		27
3	0.040	1943	0.035		1938		42
4	0.031	1943	0.027		1938		43
5	0.027	1943	0.024		1938		43
6	0.024	1943	0.022		1938		43

When the SQUEEZE Recycling converges, 43 'electrons' are Recovered from the difference density map.

This is close to the expected 42 electrons corresponding to Diethyl ether

PLATON MENU

OptionMenu

NoMove

Color

Organic

Round

Parentheses

Label-Alias

R/S-Determ

Norm-H-bond

NoSymm

Join-Expand

LstARU RCel

LstCellSymm

ListAtoms

ListBonds

LstFlagRadi

Exclude H

MinQPeakHgt

MinQPeakDis

Q-Peak-Incl

KeyInstruct

Prev Next

SAVE-InstrS

ENTRY-LIST

Reset End

Exit

MenuActive

INSTRUCTION INPUT via KEYBOARD or LEFT-MOUSE-CLICKS (HELP with RIGHT CLICKS)

>> Hit RETURN to Continue

PLATON

A Multipurpose Crystallographic Tool

(C) 1980-2008 A.L.Spek - 40M-Version: 250708

PLATON MENU

- OptionMenus
- NoMove
- Color
- Organic
- Round
- Parentheses
- Label-Alias
- R/S-Determ
- Norm-H-bond
- NoSymm
- Join-Expand
- LstARU RCel
- LstCellSymm
- ListAtoms
- ListBonds
- LstFlagRadi
- Exclude H
- MinQPeakHgt
- MinQPeakDis
- Q-Peak-Incl
- KeyInstruct
- Prev Next
- SAVE-InstrS
- ENTRY-LIST
- Reset End
- Exit
- MenuActive

GRAPHICS	GEOM-CALC	VOIDS FLIP	SYMMETRY	ABSORPTION	REPORT	MISC-TOOLS
PLATONauto	CALC ALL	CALC SOLV	ADDSYM	DELrefABS	VALIDATION	SYSTEM-S
ORTEP/ADP	CALC INTRA	CALC K.P.I	ADDSYM-EQL	ABSPsLScan	ASYM-VIEW	FCF2HKL
NEWMAN	CALC INTER	SQUEEZE	ADDSYM-EXT	ABSTampa	FCF-VALID	EXPAND-P1
RING-PLOTS	CALC COORD	CALC-FCF	ADDSYM-PLT	ABSGauss	SUPPLEMMAT	FCF-GENER
PLANE-PLOT	CALC METAL	CONTOUR-SQ	ADDSYM-SHX	ABSXtal	ANALofVAR	HKL-GENER
POLYHEDRA	CALC GEOM	SOLV F3D	NEWSYM	ABSSphere	ByvoetPatr	HKL-TRANSF
CONTOUR-DF	CALC HBOND	SOLV PLOT	NONSYM	MULscanABS	ASYM-EXPCT	EXOR-RES
CONTOUR-FO	CALC TMA	CAVITY-PLT	LEPAGE	SHXABS	ASYM-VALID	ANIS-RES
AutoMolFlt	L.S.-PLANE		DELRED		DLfFourler	RENAME-RES
HKL2Powder	DLhedAngle		MOLSYM		EXPECT-HKL	PDB -pdb
SLmPowderP	AngleLLnes		SPGRfromEX		CSD-CELL	SPF -eld
RadDlstFun	AngleSplLLn	FLIP SHOW	ASYM		CSD-QUEST	SHELXL-res
PATTERSON	CremerPopl	FLIP PATT	ASYMaverFR		StructTldy	CIF -acc
	BondValenc	FLIP ER 25	LePageTwln		StralnAnal	AUTO-RENUM
PLATONatlv	HFIX - RES	STRUC TURE?	TwlnRotMat	Xtal Habit	CIF-LOCAL	CIF2SHELXL

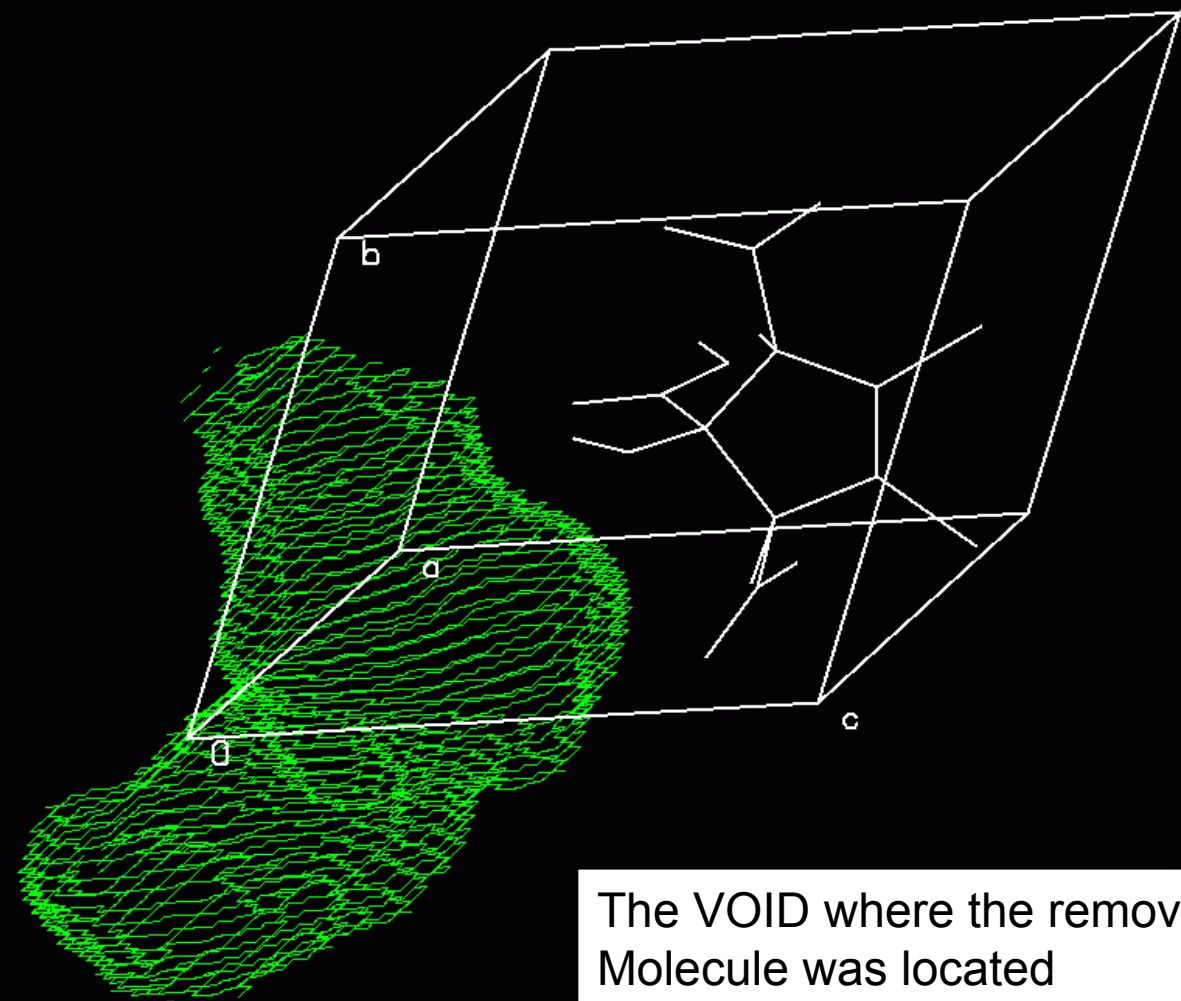


Xtal Data (RES) jorfeb lns- Set 1(1): jorfeb
 Refl Data (HKL) jorfeb hkl 5 10 01001 (0)

VOID & SQUEEZE TOOLS

HELP

INSTRUCTION INPUT via KEYBOARD or LEFT-MOUSE-CLICKS (HELP with RIGHT CLICKS)



The VOID where the removed ether Molecule was located

- SOLV MENU
- Stereo Opts
- DotsContour
- ViewX0
- ViewY0
- ViewZ0
- Reverse-B&W
- VoidAxes
- UnitSymPack
- Resd012..
- UnitFill1
- Void0123...
- UnitCellBox
- Show-Mol
- Dhashi-Vol
- LabelCell
- Label -Hat+
- LabelSize >
- <<-RotZ++>>
- <<-RotY++>>
- <<-RotX++>>
- Color
- Decoration
- EPS-File
- End
- Exit
- MenuActive

INSTRUCTION INPUT via KEYBOARD or LEFT-MOUSE-CLICKS (HELP with RIGHT CLICKS)

>> Continue (Y/N[Y])

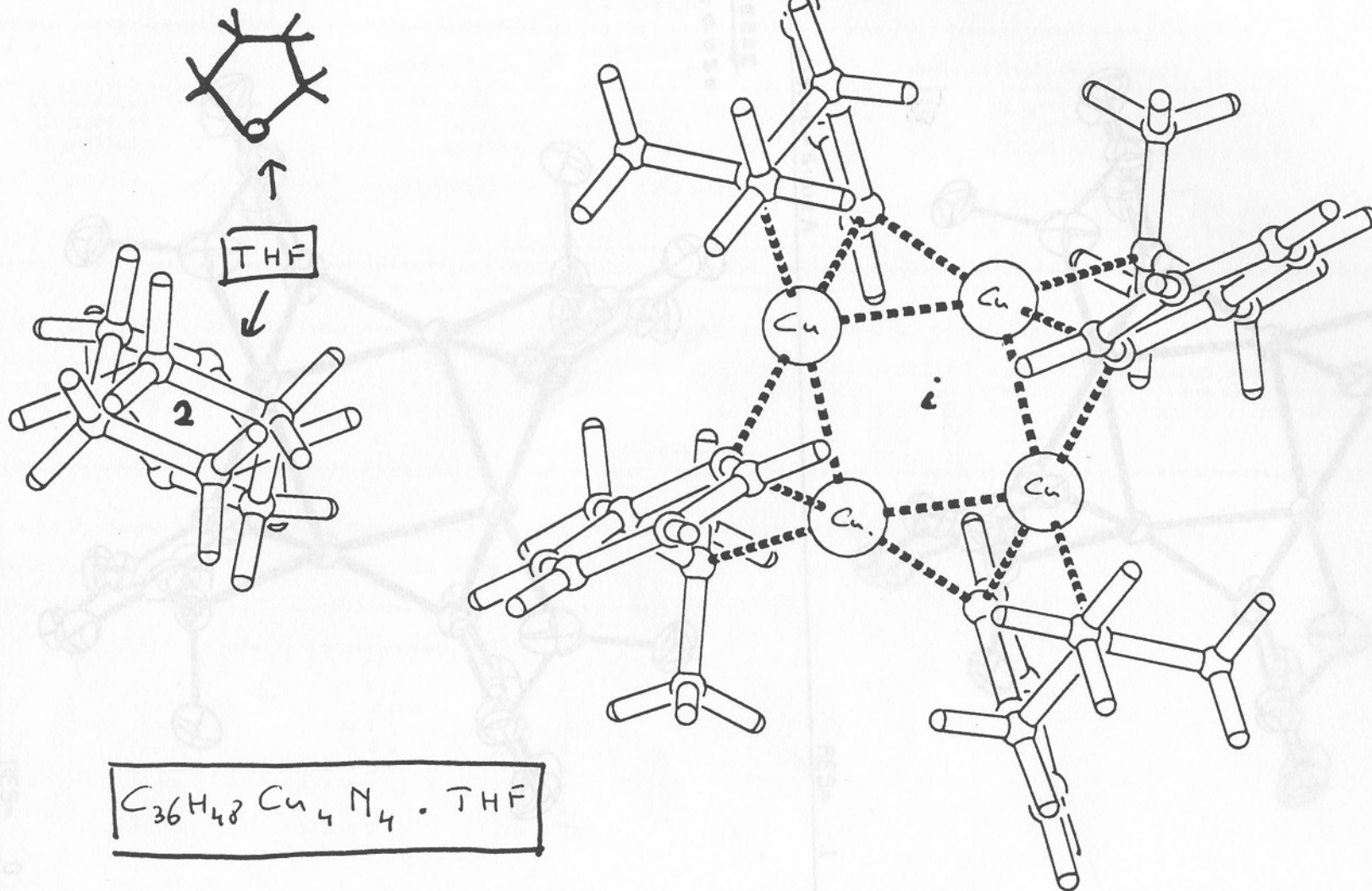
Recommended SQUEEZE Procedure in combination with SHELXL97

1. Refine a discrete atom model including Hydrogen atoms with SHELXL => **.res**
2. Delete (when applicable) all 'atoms' used to tentatively model the disordered region => **.res**
3. Do a PLATON/SQUEEZE run with **.res** (from 2) and **.hkl** (from 1)
4. Copy **.res** => **.ins** and **.hkp** => **.hkl** in a new directory
5. Refine with SHELXL (with **.ins** and **.hkl** from 4)
6. Analyze results and optionally repeat from 3 (with **.res** from 5 and original **.hkl**)
7. Do final 'CALC FCF' with PLATON to get proper **.fcf** (with **.res** and **.hkl** from 5 in a new directory) => **.hkp**
8. Rename **.hkp** => **.fcf**
9. Append the SQUEEZE info in **.sqf** to the **.cif** from 5

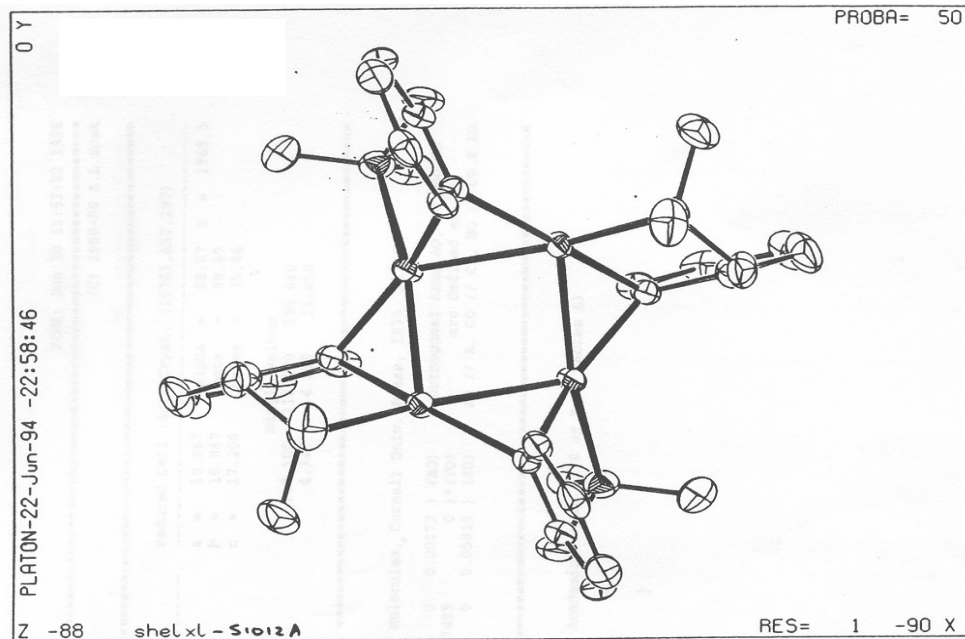
Real World Example

- THF molecule disordered over a center of inversion
- Comparison of the result of a disorder model refinement with a SQUEEZE refinement

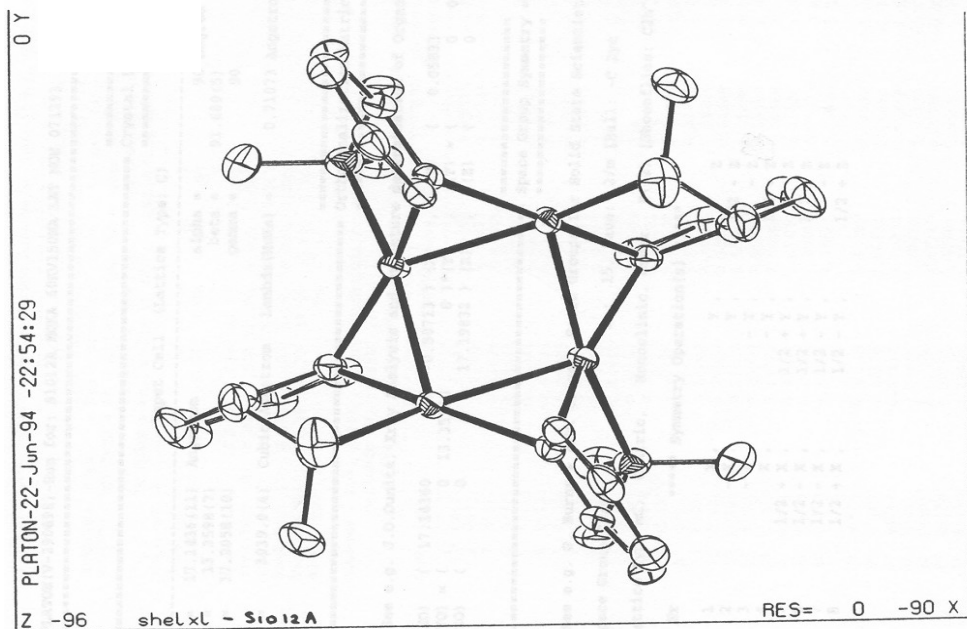
Disorder Model Refinement
Final R = 0.033



Comparison of the Results of the two Modeling Procedures



Disorder Model
 $R = 0.033$



SQUEEZE Model
 $R = 0.030$

LISTING OF FINAL SQUEEZE CYCLE RESULTS

:: Cycle = 4, R(F) = 0.04, Nref(Hemi) = 8811, R(F > 4SIGF) = 0.03 Nref = 7380

Unique Density Maxima in Enhanced Difference Map (CutOff level = 0.50 eA⁻³)

```
=====
      x      y      z  (e/A^3)  Shortest Contacts within 3.2 Angstrom (Excl. H)
=====
```

1	0.490	0.220	0.281	4.57	void
2	0.552	0.266	0.301	4.41	void
3	0.475	0.379	0.212	3.54	void
4	0.441	0.356	0.252	3.39	void
5	0.499	0.297	0.252	0.89	void
6	0.953	0.184	0.125	0.55	C16 0.68; C11 0.75; C15 1.90; C12 1.90; Cu2
7	0.408	0.253	0.501	0.51	C13 0.61; C12 0.90; C14 1.85; C17 1.97; C11
8	0.358	0.170	0.717	0.50	Cu1 1.11; C21 1.53; C22 2.11; C27 2.37; Cu2
9	0.283	0.085	0.613	0.50	C18 0.77; N1 1.75; C19 2.46; Cu1 2.82; C17

VOID Volume Ang³ Electron-Count (e-) Volume per electron Vol/Atom

```
=====
```

A	155	43	3.6	29
B	155	43	3.6	29
C	155	43	3.6	29
D	155	43	3.6	29

Total (Positive) Electron Count in Voids/Cell = 172

Total (Fo-Fc)map Electron Count in Unit Cell = 171

VOID-Fo-Fc-Map: Rho(min) = -0.28, Rho(max) = 4.57, RhoCutOff = 0.00

PeaksCloseToAtoms: Rho(min) = -0.63, Rho(max) = 0.55, RhoCutOff = 0.50

:: Fo-scale =0.210538E+01 - SinT/L-Min = 0.20 for Fo/Fc-Scaling

:: Cycle = 5, R(F) = 0.04, Nref(Hemi) = 8811, R(F > 4SIGF) = 0.03 Nref = 7380

ANALYSIS OF R-VALUE IMPROVEMENT WITH RESOLUTION

A
SQUEEZE Statistics on the Difference Map Phasing

A=====

- N
F_cMod = Average contribution to F_c from discrete model
 A F_cSolv = Average contribution to F_c from solvent region
 L F_cTot = Average F_c total (= model + solvent contrib.)
 Y DelMS = Average Phase difference between model and solvent contrib.
 Y DelMT = Average Phase difference between model and combined contrib.
 S = Number of reflections in Sin(Theta)/Lambda range
 R(Mod) = SIGMA(ABS(ABS(F_cMod) - F_o)) / SIGMA(F_o)
 S R(Tot) = SIGMA(ABS(ABS(F_cTot) - F_o)) / SIGMA(F_o)

SinT/L	<F _c Mod>	<F _c Solv>	<F _c Tot>	<F _o >	<DelMS>	<DelMT>	N	R(Mod)	R(Tot)
0.05	269.40	95.86	278.98	275.37	100.00	0.01	18.	0.336	0.033
0.10	143.62	47.76	157.32	160.98	77.17	12.87	56.	0.281	0.043
0.15	105.09	16.83	107.15	110.76	86.51	8.88	122.	0.155	0.048
0.20	114.13	8.59	115.03	116.75	87.75	3.38	210.	0.090	0.041
0.25	116.69	8.11	116.64	117.74	87.17	1.18	322.	0.080	0.038
0.30	88.12	6.28	88.18	88.41	91.33	2.29	480.	0.083	0.037
0.35	71.70	4.12	71.60	71.80	91.11	3.11	632.	0.070	0.039
0.40	60.71	3.18	60.94	60.76	87.13	1.15	842.	0.074	0.047
0.45	53.95	2.79	54.11	53.87	88.69	2.19	1036.	0.075	0.051
0.50	49.89	2.26	49.87	49.59	92.77	1.79	1262.	0.071	0.055
0.55	40.11	1.61	40.15	39.83	88.48	1.11	1138.	0.075	0.063
0.60	30.62	1.02	30.62	30.91	89.65	1.57	917.	0.089	0.078
0.65	28.65	0.86	28.69	28.90	87.74	0.51	481.	0.098	0.086

SQUEEZE REQUIREMENTS

- A Complete data set, including non-zero intensity low order reflections for the estimation of the number of electrons in the void region.
- No significant residual unresolved density excursions in the difference map for the ordered part of the structure

Limitations of SQUEEZE

- SQUEEZE can currently not handle properly most cases of main molecule disorder that is coupled with the solvent disorder.
- SQUEEZE is currently incompatible with twinning
- SQUEEZE needs a sufficient data resolution to give meaningful results

Concluding Remarks

- The CSD includes now in the order of 1000 entries where SQUEEZE was used.
- Care should be taken with issues such as charge balance that effects the chemistry involved.
- The use of the SQUEEZE procedure should be detailed in the experimental section of a paper based on its use.

Additional Info

<http://www.cryst.chem.uu.nl/platon/PLATON-MANUAL.pdf>

The Bypass Paper:

P. van der Sluis & A.L. Spek (1990). *Acta Cryst.*,
A46, 194-201.

